

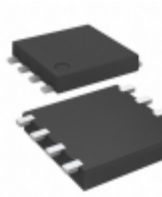

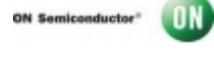



	<h2 style="color: red;">ECH8310-TL-H</h2>
	<p>Hersteller-Teilenummer: ECH8310-TL-H</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 30V 9A ECH8</p> <p>Datenblätter:  ECH8310-TL-H.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 2241 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	ECH8310-TL-H
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 30V 9A ECH8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2241 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SMD, Flat Lead
Supplier Device-Gehäuse	8-ECH
Verlustleistung (max)	1.5W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9A (Ta)
Rds On (Max) @ Id, Vgs	17 mOhm @ 4.5A, 10V
VGS (th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	28nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1400pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	4V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































ECH8310-TL-H ist neu im Original, Suche ECH8310-TL-H Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie ECH8310-TL-H AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage ECH8310-TL-H: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>ECH8315-TL-H AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 7.5A ECH8</p>	 <p>ECH8320-TL-H AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 9.5A ECH8</p>	 <p>ECH8315-TL-W AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 7.5A ECH8</p>	 <p>ECH8311-TL-H SANYO ECH8311-TL-H SANYO</p>
 <p>ECH8310-TL AMI Semiconductor / ON Semiconductor ECH8310-TL ON</p>	 <p>ECH8309-TL-H AMI Semiconductor / ON Semiconductor MOSFET P-CH 12V 9.5A ECH8</p>	 <p>ECH8308-P-TL-H AMI Semiconductor / ON Semiconductor MOSFET P-CH 12V 10A ECH8</p>	 <p>ECH8401 SANYO ECH8401 SANYO</p>

heiße Teile

Mehr

 ECH-U1C222JX5	 ECH-U1C272JX5	 ECH-U1C332JX5	 ECH-U1C562JX5	 ECH-U1H333JX5
 ECH8301-TL	 ECH8301-TL-E	 ECH8302-TL-E	 ECH8304-TL-E	 ECH8305-TL
 ECH8305-TL-E	 ECH8308-P-TL-H	 ECH8308-TL-H	 ECH8309-TL-H	 ECH8310-TL
 ECH8311-TL-H	 ECH8315-TL-H	 ECH8320-TL-H	 ECH8401-TL-E	 ECH8402-TL-E
 ECH8410-TL-H	 ECH8502-TL-H	 ECH8601-TL	 ECH8601-TL-E	 ECH8601-V-TL-E
 ECH8601M-C-TL-H	 ECH8601M-C-TL-HX	 ECH8601M-TL-H	 ECH8601R	 ECH8601R-B-TL-H
 ECH8601R-H-TL-E	 ECH8601R-TL-E	 ECH8601R-V-TL-E	 ECH8602M	 ECH8602M-TL-H
 ECH8602R-TL-H	 ECH8603-TL-E	 ECH8605-TL-H	 ECH8606-TL-E	 ECH8606-V-TL-E
 ECH8607-TL-E	 ECH8609-TL-E	 ECH8611-TL-E	 ECH8612-TL-H	 ECH8619-TL-E
 ECH8621-C-TL-E	 ECH8622-TL-E	 ECH8622R-TL-H	 ECH8649-S-TL-H	 ECH8651R-TL

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